NSN 5962-01-456-4635

Digital Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
1.5 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Electrical e/i fscm 81349
Features Provided:
Monolithic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Design Function And Quantity:
1 memory, static ram
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, memory, digital, cmos, 1k x 8 dual port static random access memory (sram), monolithic silicon
Voltage Rating And Type Per Characteristic:
-0.5 volts input and 7.0 volts input
Supplementary Features:
Circuit function - 1k x 8 bit dual port cmos sram (master), access time 45 ns (data retention)
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
48 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0